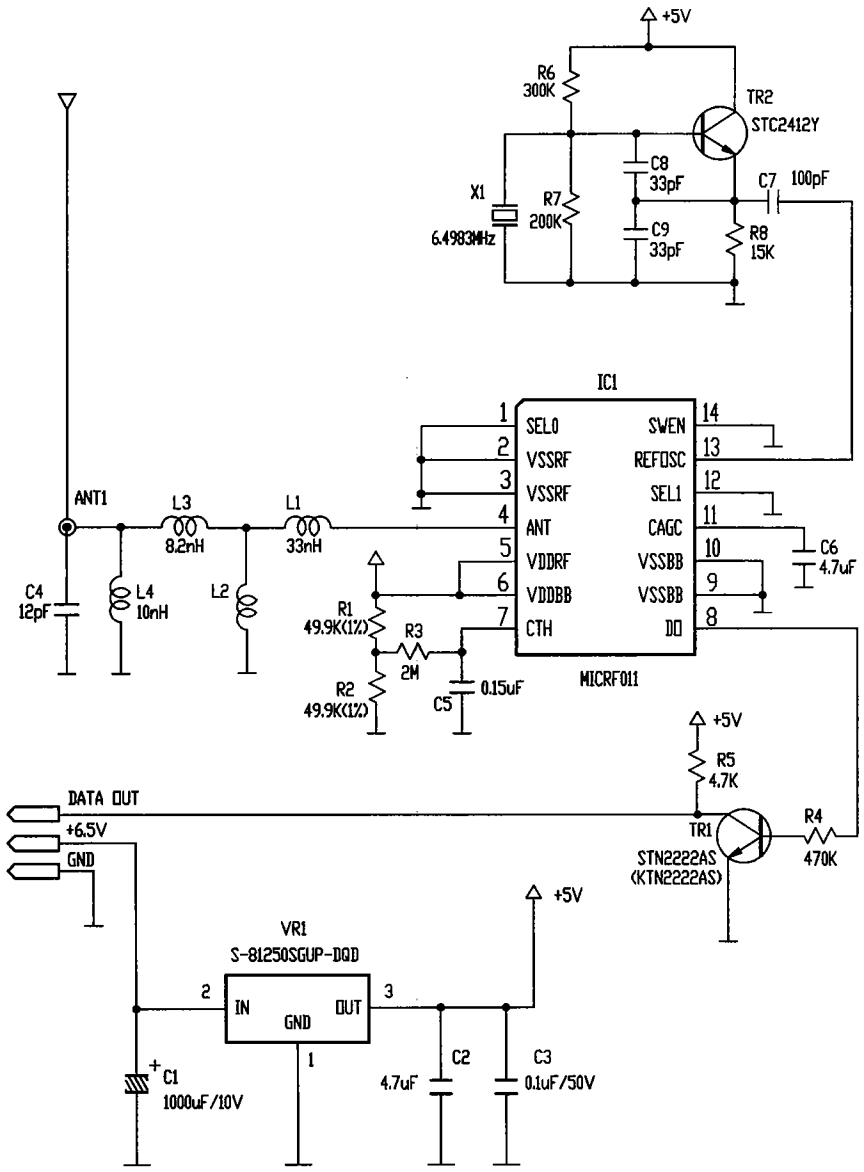


D	C	B	A	NO.	DESCRIPTION	PART NO.	MATERIAL	Q'TY	SURFACE TREATMENT	REMARK
					CIRCUIT DIAGRAM					

L No	Description	Part Number	MAKER
IC 1	UHF OOK/ASK Receiver IC	MICRF 011	Micel
VR 1	VOLTAGE REGULATOR 5.0V	S-81250SGUP-DQD	Seiko
TR 1	TR	STN 2222AS	AUK
TR 2	TR	STC 2412Y	AUK
X 1	CRYSTAL 6.4983MHz	6.4983MHz	CQ
C 1	ELEC' CAPACITOR 1000uF/10V	1000uF/10V	
L 1	Inductor, High Q , 33nH , 2012	LQN21A33NJ04	Murata
L 2	-	-	-
L 3	Inductor, High Q , 8.2nH , 2012	LQN21A8N2D04	Murata
L 4	Inductor, High Q , 10nH , 2012	LQN21A10NJ04	Murata
C 6	Ceramin Capacitor , 4.7uF X5R , 3216	GRM42-6X5R475K10	Murata
C 2	Ceramin Capacitor , 4.7uF Y5V , 3216	GRM42-6Y5V475Z16	Murata
C 5	Ceramin Capacitor , 0.15uF K , 2012	CEEMK212BJ154KG-T	TAYO YUDEN
C 4	Ceramin Capacitor , 12pF J , 2012	GRM2165C1H120JA01D	Murata
C 7	Ceramin Capacitor , 100pF J , 2012	GRM2165C1H101JA01D	Murata
C 8	Ceramin Capacitor , 33pF J , 2012	GRM2165C1H330JA01D	Murata
C 9	Ceramin Capacitor , 33pF J , 2012	GRM2165C1H330JA01D	Murata
C 3	Ceramin Capacitor , 0.1uF J , 2012	GRM2165F51E104ZA01D	Murata
R 1	Resistor , 49.9K , K , 2012	RD-	ROHM
R 2	Resistor , 49.9K , K , 2012	RD-	ROHM
R 3	Resistor , 2.0M , Z , 2012	RD-	ROHM
R 4	Resistor , 470K , Z , 2012	RD-	ROHM
R 5	Resistor , 4.7K , Z , 2012	RD-	ROHM
R 6	Resistor , 300K , Z , 2012	RD-	ROHM
R 7	Resistor , 200K , Z , 2012	RD-	ROHM
R 8	Resistor , 15K , Z , 2012	RD-	ROHM
JP 1	Resistor , 0 , 2012	RD-	ROHM
JP 2	Resistor , 0 , 2012	RD-	ROHM
JP 3	Resistor , 0 , 2012	RD-	ROHM

DATE	AUTHORIZED	CHANGED DETAILS	CHANGED BASIS

SCALE	NS	UNIT	MM	LIMIT		DESCRIPTION	CIRCUIT DIAGRAM
Drafter		Checked		Approved			
JH Park						P/NO.	
06.06.09							
CH.SUNG ELECTRONICS CO.,LTD.		REF. NO.		LG DAV		DRAFT NO.	
		STOCK NO.					

A3(420X297)